Abstract:

The invention relates to a sub-20 nm nanofiller for use in a matrix material, to the matrix resulting therefrom, to a process for preparing said matrix, and to the use of said nanofiller, the nanofiller comprising functionalized polyhedral oligomeric silicon-oxygen cluster units of the formula

$$[(R_aX_bSiO_{1.5})_m (R_cX_dSiO)_n (R_eX_fSi_2O_{2.5})_o (R_gX_hSi_2O_2)_p]$$

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a, b, c = 0-1; d = 1-2; e, g, f = 0-3; h = 1-4;
$$m \cdot b + n \cdot d + o \cdot f + p \cdot h \le 4; m + n + o + p \ge 4; a + b = 1; c + d = 2; e + f = 3 \text{ and } g + h = 4;$$

- R = hydrogen atom, alkyl, cycloalkyl, alkenyl, cycloalkenyl, alkynyl, cycloalkynyl, aryl, heteroaryl group or polymer unit, which are in each case substituted or unsubstituted, or further functionalized polyhedral oligomeric silicon-oxygen cluster units, which are attached by way of a polymer unit or a bridging unit,
- X = oxy, hydroxyl, alkoxy, carboxyl, silyl, alkylsilyl, alkoxysilyl, siloxy, alkylsiloxy, alkoxysiloxy, silylalkyl, alkoxysilylalkyl, alkylsilylalkyl, halogen, epoxy, ester, fluoroalkyl, isocyanate, blocked isocyanate, acrylate, methacrylate, nitrile, amino, phosphine group or substituents of the type R containing at least one such group of the type X,

the substituents of the type R being identical or different and the substituents of the type X being identical or different, with the proviso that there are not more than four substituents of the type X per cluster unit.